Triple 2-channel analog multiplexer/demultiplexerRev. 11 — 9 September 2021Product data sheet

1. General description

The 74HC4053; 74HCT4053 is a triple single-pole double-throw analog switch (3x SPDT) suitable for use in analog or digital 2:1 multiplexer/demultiplexer applications. Each switch features a digital select input (Sn), two independent inputs/outputs (nY0 and nY1) and a common input/output (nZ). A digital enable input (Ē) is common to all switches. When Ē is HIGH, the switches are turned off. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

2. Features and benefits

- Wide analog input voltage range from -5 V to +5 V
- CMOS low power dissipation
- High noise immunity
- Latch-up performance exceeds 100 mA per JESD78 Class II Level B
- Complies with JEDEC standard:
 - JESD8C (2.7 V to 3.6 V)
 - JESD7A (2.0 V to 6.0 V)
 - Low ON resistance:
 - 80 Ω (typical) at V_{CC} V_{EE} = 4.5 V
 - 70 Ω (typical) at V_{CC} V_{EE} = 6.0 V
 - 60 Ω (typical) at V_{CC} V_{EE} = 9.0 V
- Logic level translation: to enable 5 V logic to communicate with ±5 V analog signals
- Typical 'break before make' built-in
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

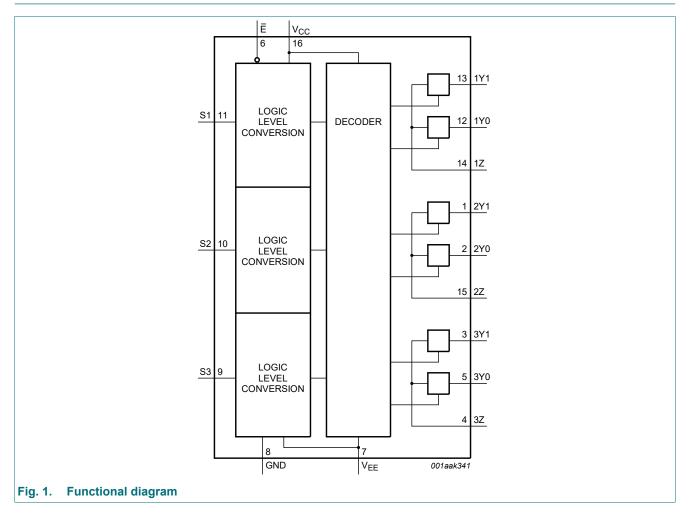
- Analog multiplexing and demultiplexing
- Digital multiplexing and demultiplexing
- Signal gating



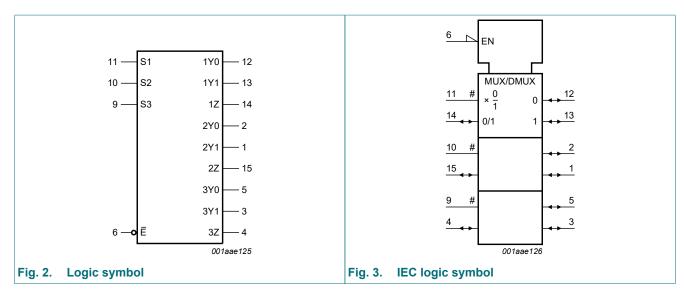
4. Ordering information

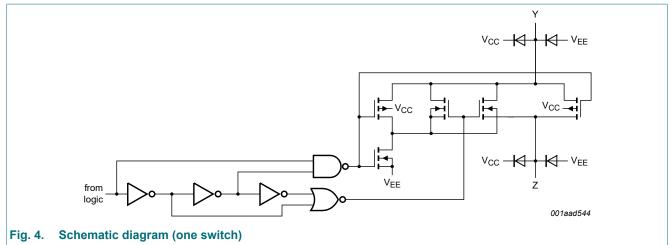
Type number	Package							
	Temperature range	Name	Description	Version				
74HC4053D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1				
74HCT4053D			body width 3.9 mm					
74HC4053PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1				
74HCT4053PW			body width 4.4 mm					
74HC4053BQ	-40 °C to +125 °C	DHVQFN16	1	SOT763-1				
74HCT4053BQ			very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm					

5. Functional diagram



Triple 2-channel analog multiplexer/demultiplexer

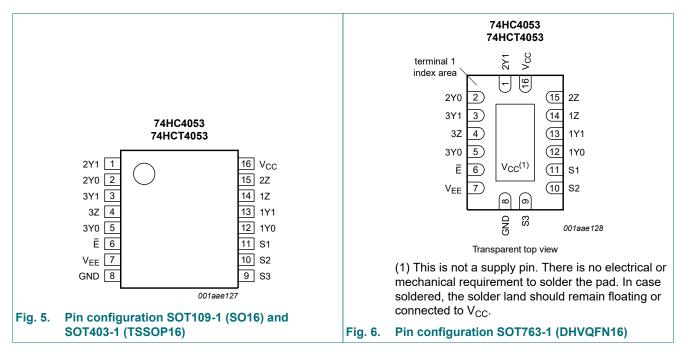




Product data sheet

© Nexperia B.V. 2021. All rights reserved

6. Pinning information



6.1. Pinning

6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
E	6	enable input (active LOW)
V _{EE}	7	supply voltage
GND	8	ground supply voltage
S1, S2, S3	11, 10, 9	select input
1Y0, 2Y0, 3Y0	12, 2, 5	independent input or output
1Y1, 2Y1, 3Y1	13, 1, 3	independent input or output
1Z, 2Z, 3Z	14, 15, 4	common output or input
V _{cc}	16	supply voltage

7. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level; X = don't care.

Inputs		Channel on
E	Sn	
L	L	nY0 to nZ
L	Н	nY1 to nZ
Н	X	switches off

74HC_HCT4053

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage	[1]	-0.5	+11.0	V
I _{IK}	input clamping current	V_{I} < -0.5 V or V_{I} > V_{CC} + 0.5 V	-	±20	mA
I _{SK}	switch clamping current	$V_{\rm SW}$ < -0.5 V or $V_{\rm SW}$ > $V_{\rm CC}$ + 0.5 V	-	±20	mA
I _{SW}	switch current	$-0.5 V < V_{SW} < V_{CC} + 0.5 V$	-	±25	mA
I _{EE}	supply current		-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	[2]	-	500	mW
Р	power dissipation	per switch	-	100	mW

[1] To avoid drawing V_{CC} current out of terminal nZ, when switch current flows into terminals nYn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal nZ, no V_{CC} current will flow out of terminals nYn, and in this case there is no limit for the voltage drop across the switch, but the voltages at nYn and nZ may not exceed V_{CC} or V_{EE} .

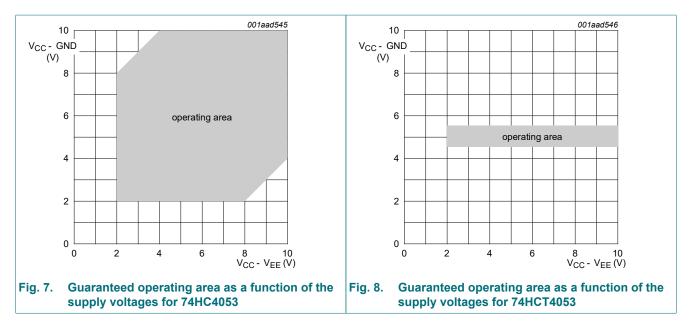
[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C. For SOT763-1 (DHVQFN16) package: P_{tot} derates linearly with 11.2 mW/K above 106 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	7	74HC405	3	7	4HCT405	53	Unit
			Min	Тур	Max	Min	Тур	Max	-
V _{CC}	supply voltage	see <u>Fig. 7</u> and <u>Fig. 8</u>							
		V _{CC} - GND	2.0	5.0	10.0	4.5	5.0	5.5	V
		V _{CC} - V _{EE}	2.0	5.0	10.0	2.0	5.0	10.0	V
VI	input voltage		GND	-	V _{CC}	GND	-	V _{CC}	V
V _{SW}	switch voltage		V _{EE}	-	V _{CC}	V _{EE}	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall	V _{CC} = 2.0 V	-	-	625	-	-	-	ns/V
	rate	V _{CC} = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V _{CC} = 6.0 V	-	-	83	-	-	-	ns/V
		V _{CC} = 10.0 V	-	-	31	-	-	-	ns/V

Triple 2-channel analog multiplexer/demultiplexer



10. Static characteristics

Table 6. R_{ON} resistance per switch for 74HC4053 and 74HCT4053

 $V_I = V_{IH}$ or V_{IL} ; for test circuit see Fig. 9.

Vis is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

For 74HC4053: V_{CC} - GND or V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

For 74HCT4053: V_{CC} - GND = 4.5 V and 5.5 V, V_{CC} - V_{EE} = 2.0 V, 4.5 V, 6.0 V and 9.0 V.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 25	5 °C				1		
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	100	180	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	90	160	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	70	130	Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} = V _{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	150	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	80	140	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	70	120	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	60	105	Ω
		V _{is} = V _{CC}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	150	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	90	160	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	80	140	Ω
		V_{CC} = 4.5 V; V_{EE} = -4.5 V; I_{SW} = 1000 µA		-	65	120	Ω
ΔR _{ON}	ON resistance mismatch	$V_{is} = V_{CC}$ to V_{EE}					
	between channels	V _{CC} = 2.0 V; V _{EE} = 0 V	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	9	-	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V		-	8	-	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	6	-	Ω

74HC_HCT4053

Triple 2-channel analog multiplexer/demultiplexer

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C						_
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	225	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	200	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	165	Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} = V _{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	175	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	150	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	130	Ω
		V _{is} = V _{CC}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	200	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	175	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	150	Ω
T _{amb} = -4	0 °C to +125 °C						
R _{ON(peak)}	ON resistance (peak)	$V_{is} = V_{CC}$ to V_{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	270	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	240	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	195	Ω
R _{ON(rail)}	ON resistance (rail)	V _{is} = V _{EE}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	210	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	180	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	160	Ω
		V _{is} = V _{CC}					
		V _{CC} = 2.0 V; V _{EE} = 0 V; I _{SW} = 100 μA	[1]	-	-	-	Ω
		V _{CC} = 4.5 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	240	Ω
		V _{CC} = 6.0 V; V _{EE} = 0 V; I _{SW} = 1000 μA		-	-	210	Ω
		V _{CC} = 4.5 V; V _{EE} = -4.5 V; I _{SW} = 1000 μA		-	-	180	Ω

[1] When supply voltages ($V_{CC} - V_{EE}$) near 2.0 V the analog switch ON resistance becomes extremely non-linear. When using a supply of 2 V, it is recommended to use these devices only for transmitting digital signals.

Triple 2-channel analog multiplexer/demultiplexer

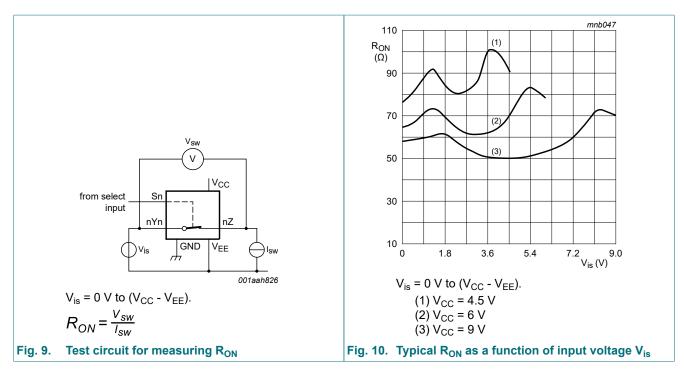


Table 7. Static characteristics for 74HC4053

Voltages are referenced to GND (ground = 0 V).

 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

Vos is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C				1	
V _{IH}	HIGH-level input	V _{CC} = 2.0 V	1.5	1.2	-	V
	voltage	V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
		V _{CC} = 9.0 V	6.3	4.7	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	0.8	0.5	V
	voltage	V _{CC} = 4.5 V	-	2.1	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	V
		V _{CC} = 9.0 V	-	4.3	2.7	V
II.	input leakage current	V _{EE} = 0 V; V _I = V _{CC} or GND				
		V _{CC} = 6.0 V	-	-	±0.1	μA
		V _{CC} = 10.0 V	-	-	±0.2	μA
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 11</u>				
		per channel	-	-	±0.1	μA
		all channels	-	-	±0.1	μA
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 12</u>	-	-	±0.1	μA
I _{CC}	supply current	V_{EE} = 0 V; V _I = V _{CC} or GND; V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE}				
		V _{CC} = 6.0 V	-	-	8.0	μA
		V _{CC} = 10.0 V	-	-	16.0	μA
Cı	input capacitance		-	3.5	-	pF

Triple 2-channel analog multiplexer/demultiplexer

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	8	-	pF
T _{amb} = -4	40 °C to +85 °C					
VIH	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
I _I	input leakage	V _{EE} = 0 V; V _I = V _{CC} or GND				
	current	V _{CC} = 6.0 V	-	-	±1.0	μA
		V _{CC} = 10.0 V	-	-	±2.0	μA
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; Fig. 11				
		per channel	-	-	±1.0	μA
		all channels	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 12</u>	-	-	±1.0	μA
I _{CC}	supply current	V_{EE} = 0 V; V _I = V _{CC} or GND; V _{is} = V _{EE} or V _{CC} ; V _{os} = V _{CC} or V _{EE}				
		V _{CC} = 6.0 V	-	-	80.0	μA
		V _{CC} = 10.0 V	-	-	160.0	μA
T _{amb} = -4	40 °C to +125 °C					
VIH	HIGH-level input	V _{CC} = 2.0 V	1.5	-	-	V
	voltage	V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
		V _{CC} = 9.0 V	6.3	-	-	V
V _{IL}	LOW-level input	V _{CC} = 2.0 V	-	-	0.5	V
	voltage	V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
		V _{CC} = 9.0 V	-	-	2.7	V
l _l	input leakage	V _{EE} = 0 V; V _I = V _{CC} or GND				
	current	V _{CC} = 6.0 V	-	-	±1.0	μA
		V _{CC} = 10.0 V	-	-	±2.0	μA
I _{S(OFF)}	OFF-state leakage current	V _{CC} = 10.0 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see <u>Fig. 11</u>				
		per channel	-	-	±1.0	μA
		all channels	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	V _{CC} = 10.0 V; V _{EE} = 0 V; V _I = V _{IH} or V _{IL} ; V _{SW} = V _{CC} - V _{EE} ; see <u>Fig. 12</u>	-	-	±1.0	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CC}	supply current					
		V _{CC} = 6.0 V	-	-	160.0	μA
		V _{CC} = 10.0 V	-	-	320.0	μA

Table 8. Static characteristics for 74HCT4053

Voltages are referenced to GND (ground = 0 V).

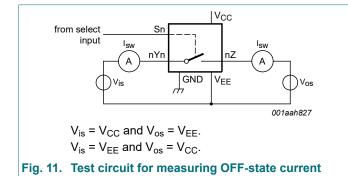
 V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

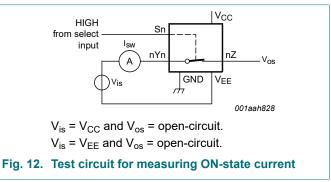
Vos is the output voltage at pins nZ or nYn, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C				1	
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
II	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±0.1	μA
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±0.1	μA
		all channels	-	-	±0.1	μA
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±0.1	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	8.0	μA
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	16.0	μA
∆I _{CC}	additional supply current	per input; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; V _{EE} = 0 V	-	50	180	μA
CI	input capacitance		-	3.5	-	pF
C _{sw}	switch capacitance	independent pins nYn	-	5	-	pF
		common pins nZ	-	8	-	pF
T _{amb} = -	40 °C to +85 °C				-	
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
lı	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±1.0	μA
I _{S(OFF)}	OFF-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 11$				
		per channel	-	-	±1.0	μA
		all channels	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	$V_{CC} = 10.0 \text{ V}; V_{EE} = 0 \text{ V}; V_I = V_{IH} \text{ or } V_{IL};$ $ V_{SW} = V_{CC} - V_{EE}; \text{ see } Fig. 12$	-	-	±1.0	μA
I _{CC}	supply current	V_{I} = V_{CC} or GND; V_{is} = V_{EE} or V_{CC} ; V_{os} = V_{CC} or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	80.0	μA
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	160.0	μA

Triple 2-channel analog multiplexer/demultiplexer

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ΔI _{CC}	additional supply current	per input; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; V _{EE} = 0 V	-	-	225	μA
T _{amb} = -4	40 °C to +125 °C					_
V _{IH}	HIGH-level input voltage	V _{CC} = 4.5 V to 5.5 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 4.5 V to 5.5 V	-	-	0.8	V
lı	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $V_{EE} = 0$ V	-	-	±1.0	μA
I _{S(OFF)}	OFF-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 11</u>				
		per channel	-	-	±1.0	μA
		all channels	-	-	±1.0	μA
I _{S(ON)}	ON-state leakage current	V_{CC} = 10.0 V; V_{EE} = 0 V; V_{I} = V_{IH} or V_{IL} ; $ V_{SW} $ = V_{CC} - V_{EE} ; see <u>Fig. 12</u>	-	-	±1.0	μA
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $V_{is} = V_{EE}$ or V_{CC} ; $V_{os} = V_{CC}$ or V_{EE}				
		V _{CC} = 5.5 V; V _{EE} = 0 V	-	-	160.0	μA
		V _{CC} = 5.0 V; V _{EE} = -5.0 V	-	-	320.0	μA
∆I _{CC}	additional supply current	per input; V _I = V _{CC} - 2.1 V; other inputs at V _{CC} or GND; V _{CC} = 4.5 V to 5.5 V; V _{EE} = 0 V	-	-	245	μA





11. Dynamic characteristics

Table 9. Dynamic characteristics for 74HC4053

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; for test circuit see Fig. 15.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

Vos is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see <u>Fig. 13</u> [1]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	15	60	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	5	12	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	4	10	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	4	8	ns

Triple 2-channel analog multiplexer/demultiplexer

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = $\infty \Omega$; see <u>Fig. 14</u> [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	60	220	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	20	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	17	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	16	37	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	31	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Fig. 14 [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	75	220	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	25	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	21	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	20	37	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	31	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 kΩ; see <u>Fig. 14</u> [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	63	210	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	21	42	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	18	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	17	36	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	29	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Fig. 14 [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	60	210	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	20	42	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF	-	17	-	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	16	36	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	15	29	ns
C _{PD}	power dissipation capacitance	per switch; $V_I = GND$ to V_{CC} [4]	-	36	-	pF
$T_{amb} = -4$	40 °C to +85 °C			I	1	
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Fig. 13 [1]				
P.		$V_{CC} = 2.0 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	75	ns
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	15	ns
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	13	ns
		V _{CC} = 4.5 V; V _{FF} = -4.5 V	-	-	10	ns
t _{on}	turn-on time	E to V _{os} ; R _L = ∞ Ω; see Fig. 14 [2]				
on .		$V_{CC} = 2.0 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	275	ns
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	55	ns
		$V_{CC} = 6.0 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	_	_	47	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$	-	_	39	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Fig. 14 [2]				
		$V_{CC} = 2.0 \text{ V}; \text{ V}_{EE} = 0 \text{ V}$	-	-	275	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = 0 \text{ V}$	_	-	55	ns
		$V_{CC} = 4.0 \text{ V}, V_{EE} = 0 \text{ V}$ $V_{CC} = 6.0 \text{ V}; V_{EE} = 0 \text{ V}$	_	-	47	ns
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$			39	ns

74HC_HCT4053

Triple 2-channel analog multiplexer/demultiplexer

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Fig. 14</u> [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	53	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	45	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	36	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see <u>Fig. 14</u> [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	265	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	53	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	45	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	36	ns
T _{amb} = -4	40 °C to +125 °C					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Fig. 13 [1]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	90	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	12	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = $\infty \Omega$; see <u>Fig. 14</u> [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	330	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns
		Sn to V_{os} ; $R_L = \infty \Omega$; see Fig. 14 [2]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	330	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	56	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 kΩ; see <u>Fig. 14</u> [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	315	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	63	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	54	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	44	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see Fig. 14 [3]				
		V _{CC} = 2.0 V; V _{EE} = 0 V	-	-	315	ns
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	63	ns
		V _{CC} = 6.0 V; V _{EE} = 0 V	-	-	54	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	44	ns

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_{on} is the same as t_{PZH and} t_{PZL}.
[3] t_{off} is the same as t_{PHZ} and t_{PLZ}.
[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} \times N + \Sigma \{(C_{L} + C_{sw}) \times V_{CC}^{2} \times f_{o}\} \text{ where:}$

 f_i = input frequency in MHz; f_o = output frequency in MHz;

N = number of inputs switching; Σ {(C_L + C_{sw}) × V_{CC}² × f_o} = sum of outputs;

 C_L = output load capacitance in pF; C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

Table 10. Dynamic characteristics for 74HCT4053

GND = 0 V; $t_r = t_f = 6 ns$; $C_L = 50 pF$; for test circuit see Fig. 15.

 V_{is} is the input voltage at a nYn or nZ terminal, whichever is assigned as an input.

 V_{os} is the output voltage at a nYn or nZ terminal, whichever is assigned as an output.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
T _{amb} = 2	25 °C	·					
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Fig. 13	[1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	5	12	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	4	8	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = 1 kΩ; see <u>Fig. 14</u>	[2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	27	48	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	23	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	16	34	ns
		Sn to V_{os} ; R_L = 1 k Ω ; see Fig. 14	[2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	25	48	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	21	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	16	34	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 kΩ; see <u>Fig. 14</u>	[3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	24	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	20	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	15	31	ns
		Sn to V_{os} ; R_L = 1 k Ω ; see <u>Fig. 14</u>	[3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	22	44	ns
		V _{CC} = 5.0 V; V _{EE} = 0 V; C _L = 15 pF		-	19	-	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	15	31	ns
C _{PD}	power dissipation capacitance	per switch; V_1 = GND to V_{CC} - 1.5 V	[4]	-	36	-	pF
T _{amb} = -	40 °C to +85 °C				1	1	
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Fig. 13	[1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	15	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	10	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = 1 kΩ; see <u>Fig. 14</u>	[2]				_
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	60	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	43	ns
		Sn to V_{os} ; R_L = 1 k Ω ; see <u>Fig. 14</u>	[2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	60	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	43	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 kΩ; see <u>Fig. 14</u>	[3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	55	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	39	ns
		Sn to V_{os} ; $R_L = 1 \text{ k}\Omega$; see Fig. 14	[3]				+
		V _{CC} = 4.5 V; V _{EE} = 0 V		-	-	55	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V		-	-	39	ns

Triple 2-channel analog multiplexer/demultiplexer

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	40 °C to +125 °C				1	
t _{pd}	propagation delay	V_{is} to V_{os} ; $R_L = \infty \Omega$; see Fig. 13 [1]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	18	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	12	ns
t _{on}	turn-on time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Fig. 14</u> [2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	72	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	51	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see Fig. 14 [2]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	72	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	51	ns
t _{off}	turn-off time	\overline{E} to V _{os} ; R _L = 1 k Ω ; see <u>Fig. 14</u> [3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns
		Sn to V_{os} ; $R_L = 1 k\Omega$; see Fig. 14 [3]				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	-	66	ns
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	-	47	ns

 t_{pd} is the same as t_{PHL} and $t_{\text{PLH}}.$ [1]

[2] t_{on} is the same as t_{PZH and} t_{PZL}.

 t_{off} is the same as t_{PHZ} and t_{PLZ} . [3]

[4] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma \{(C_L + C_{sw}) \times V_{CC}^2 \times f_o\}$ where:

 f_i = input frequency in MHz; f_o = output frequency in MHz;

N = number of inputs switching; Σ {(C_L + C_{sw}) × V_{CC}² × f_o} = sum of outputs;

 C_L = output load capacitance in pF; C_{sw} = switch capacitance in pF;

 V_{CC} = supply voltage in V.

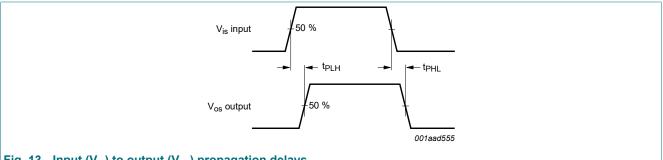


Fig. 13. Input (V_{is}) to output (V_{os}) propagation delays

Triple 2-channel analog multiplexer/demultiplexer

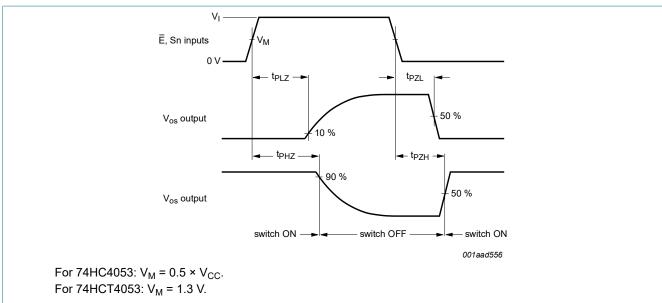


Fig. 14. Turn-on and turn-off times

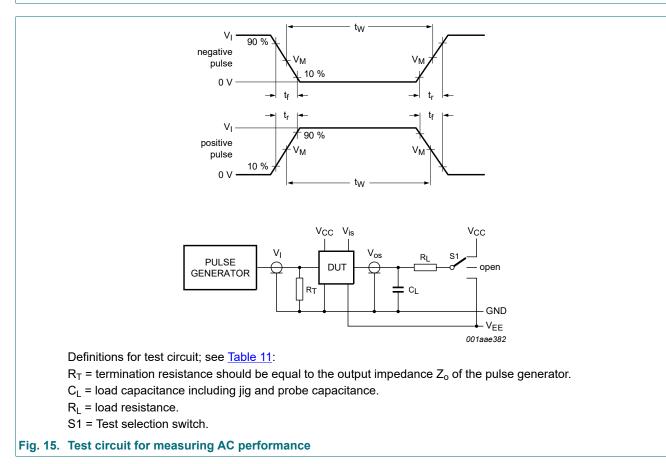


Table 11. Test data

Test	Input				Load	Load		
	V _I [1]	V _{is}	t _r , t _f	t _r , t _f		RL		
			at f _{max}	other [2]				
t _{PHL} , t _{PLH}	V _{CC}	pulse	< 2 ns	6 ns	50 pF	1 kΩ	open	
t _{PZH} , t _{PHZ}	V _{CC}	V _{CC}	< 2 ns	6 ns	50 pF	1 kΩ	V _{EE}	
t _{PZL} , t _{PLZ}	V _{CC}	V _{EE}	< 2 ns	6 ns	50 pF	1 kΩ	V _{CC}	

[1] For 74HCT4053: V_I = 3 V

[2] $t_r = t_f = 6$ ns; when measuring f_{max} , there is no constraint to t_r and t_f with 50 % duty factor.

11.1. Additional dynamic characteristics

Table 12. Additional dynamic characteristics

Recommended conditions and typical values; GND = 0 V; $T_{amb} = 25 °C$; $C_L = 50 pF$. V_{is} is the input voltage at pins nYn or nZ, whichever is assigned as an input.

 V_{os} is the output voltage at pins nYn or nZ, whichever is assigned as an output.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
d _{sin}	sine-wave distortion	$f_i = 1 \text{ kHz}; R_L = 10 \text{ k}\Omega; \text{ see } \frac{\text{Fig. 16}}{1000}$				
		V _{is} = 4.0 V (p-p); V _{CC} = 2.25 V; V _{EE} = -2.25 V	-	0.04	-	%
		V _{is} = 8.0 V (p-p); V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	0.02	-	%
		f _i = 10 kHz; R _L = 10 kΩ; see <u>Fig. 16</u>				
		V _{is} = 4.0 V (p-p); V _{CC} = 2.25 V; V _{EE} = -2.25 V	-	0.12	-	%
		V _{is} = 8.0 V (p-p); V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	0.06	-	%
α_{iso}	isolation (OFF-state)	$R_L = 600 \Omega; f_i = 1 MHz; see Fig. 17$				
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$ [1]	-	-50	-	dB
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$ [1]	-	-50	-	dB
Xtalk	crosstalk	between two switches/multiplexers; R_L = 600 Ω ; f_i = 1 MHz; see Fig. 18				
		$V_{CC} = 2.25 \text{ V}; V_{EE} = -2.25 \text{ V}$ [1]	-	-60	-	dB
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$ [1]	-	-60	-	dB
V _{ct}	crosstalk voltage	peak-to-peak value; between control and any switch; $R_L = 600 \Omega$; $f_i = 1 MHz$; E or Sn square wave between V _{CC} and GND; $t_r = t_f = 6 ns$; see Fig. 19				
		V _{CC} = 4.5 V; V _{EE} = 0 V	-	110	-	mV
		V _{CC} = 4.5 V; V _{EE} = -4.5 V	-	220	-	mV
f _(-3dB)	-3 dB frequency	R _L = 50 Ω; see <u>Fig. 20</u>				
	response	V _{CC} = 2.25 V; V _{EE} = -2.25 V [2]	-	160	-	MHz
		$V_{CC} = 4.5 \text{ V}; V_{EE} = -4.5 \text{ V}$ [2]	-	170	-	MHz

[1] Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).

[2] Adjust input voltage V_{is} to 0 dBm level at V_{os} for 1 MHz (0 dBm = 1 mW into 50 Ω).

Triple 2-channel analog multiplexer/demultiplexer

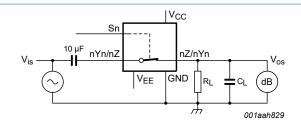
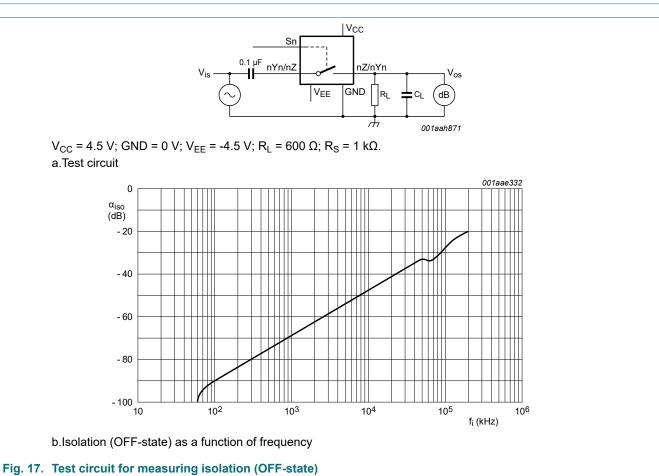
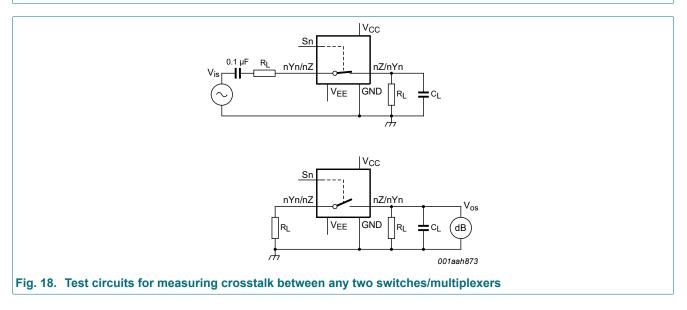


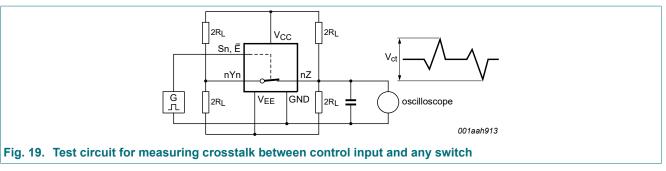
Fig. 16. Test circuit for measuring sine-wave distortion

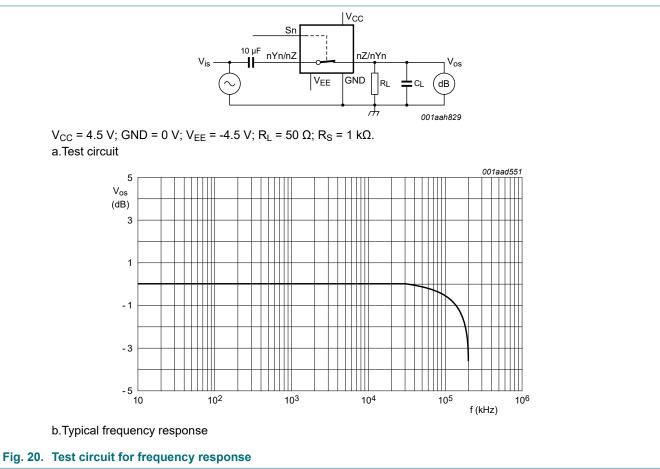




All information provided in this document is subject to legal disclaimers

Triple 2-channel analog multiplexer/demultiplexer





Product data sheet

12. Package outline

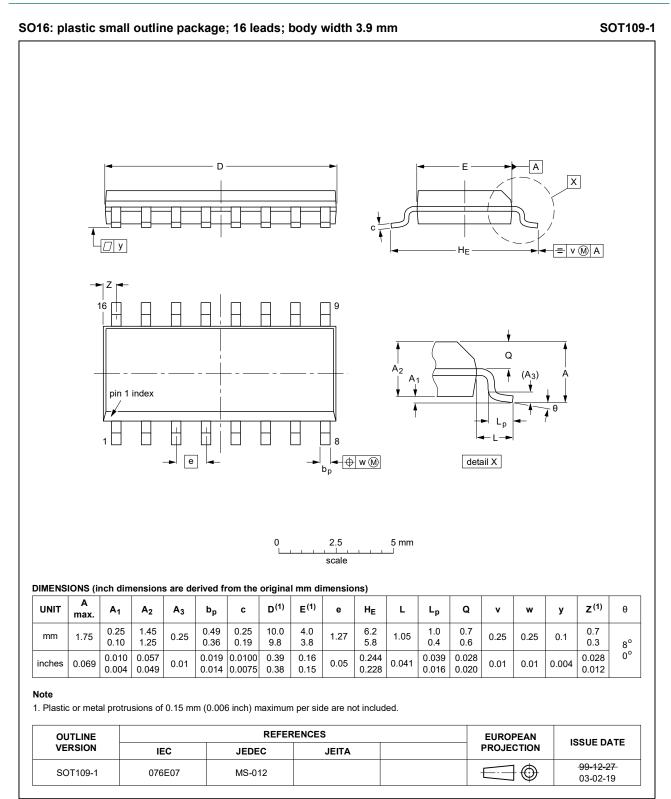


Fig. 21. Package outline SOT109-1 (SO16)

74HC_HCT4053

Triple 2-channel analog multiplexer/demultiplexer

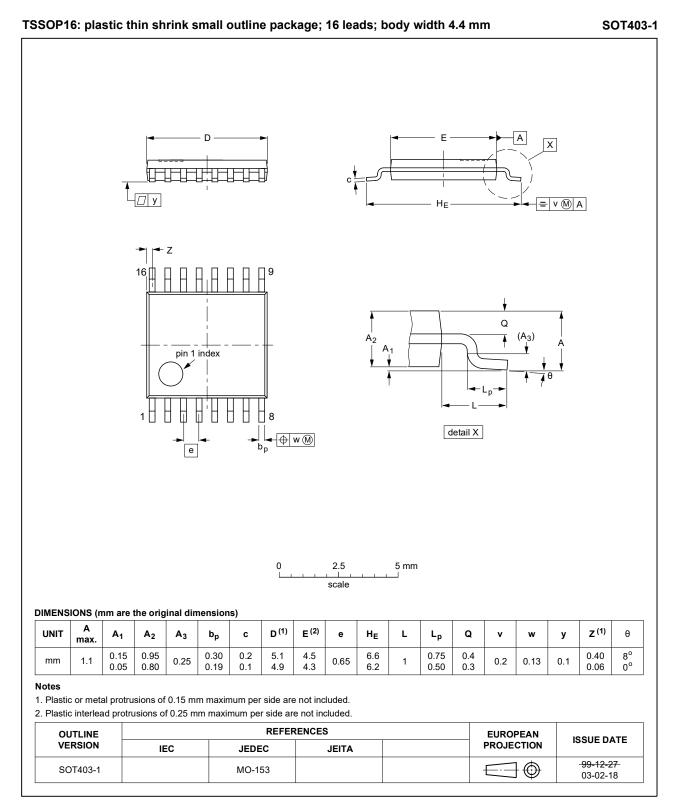


Fig. 22. Package outline SOT403-1 (TSSOP16)

⁷⁴HC_HCT4053

Triple 2-channel analog multiplexer/demultiplexer

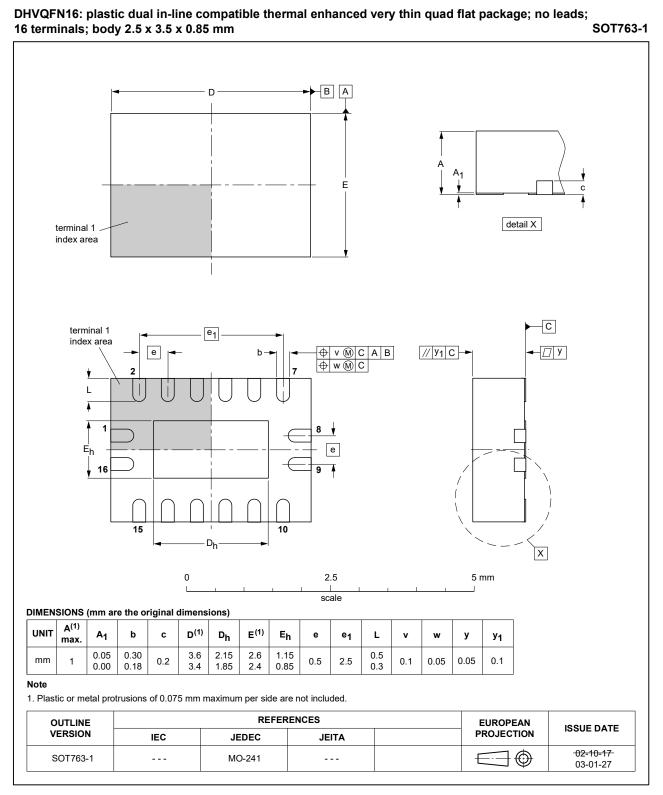


Fig. 23. Package outline SOT763-1 (DHVQFN16)

⁷⁴HC_HCT4053

13. Abbreviations

Acronym	Description	
CDM	Charged Device Model	
ESD	ElectroStatic Discharge	
НВМ	Human Body Model	
MM	Machine Model	

14. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74HC_HCT4053 v.11	20210909	Product data sheet	-	74HC_HCT4053 v.10			
Modifications:	Type number <u>Section 2</u> up	er 74HC4053DB (SOT338- pdated.	1/SSOP16) remo	ved.			
74HC_HCT4053 v.10	20200305	Product data sheet	-	74HC_HCT4053 v.9			
Modifications:	guidelines of Legal texts Type number	 Legal texts have been adapted to the new company name where appropriate. 					
74HC_HCT4053 v.9	20160210	Product data sheet	-	74HC_HCT4053 v.8			
Modifications:	Type number	ers 74HC4053N and 74HC	T4053N (SOT38-	4) removed.			
74HC_HCT4053 v.8	20120719	Product data sheet	-	74HC_HCT4053 v.7			
Modifications:	CDM addec	to features.					
74HC_HCT4053 v.7	20111213	Product data sheet	-	74HC_HCT4053 v.6			
Modifications:	Legal pages	s updated.					
74HC_HCT4053 v.6	20110511	Product data sheet	-	74HC_HCT4053 v.5			
74HC_HCT4053 v.5	20110118	Product data sheet	-	74HC_HCT4053 v.4			
74HC_HCT4053 v.4	20060509	Product data sheet	-	74HC_HCT4053 v.3			
74HC_HCT4053 v.3	20060315	Product data sheet	-	74HC_HCT4053_CNV v.2			
74HC_HCT4053_CNV v.2	19901201	Product specification	-	-			

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal

Triple 2-channel analog multiplexer/demultiplexer

injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <u>http://www.nexperia.com/profile/terms</u>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Ordering information	2
5. Functional diagram	2
6. Pinning information	4
6.1. Pinning	4
6.2. Pin description	4
7. Functional description	4
8. Limiting values	5
9. Recommended operating conditions	5
10. Static characteristics	6
11. Dynamic characteristics	11
11.1. Additional dynamic characteristics	17
12. Package outline	20
13. Abbreviations	23
14. Revision history	23
15. Legal information	24

© Nexperia B.V. 2021. All rights reserved

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com Date of release: 9 September 2021

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Multiplexer Switch ICs category:

Click to view products by Nexperia manufacturer:

Other Similar products are found below :

NLV74HC4066ADR2G HEF4051BP MC74HC4067ADTG DG508AAK/883B NLV14051BDG 016400E PI3V512QE 7705201EC PI2SSD3212NCE NLAS3257CMX2TCG PI3DBS12412AZLEX PI3V512QEX PI3DBS16213ZLEX PI3DBS16415ZHEX MUX36S16IRSNR 74LVC1G3157GM-Q10X TC7W53FK,LF CD4053BM96 MC74HC4053ADWR2G SN74LV4051APWR HEF4053BT.653 ADG5408BRUZ-REEL7 ADG1404YRUZ-REEL7 ADG1208YRZ-REEL7 MAX4704EUB+T ADG1406BRUZ-REEL7 LTC4305IDHD#PBF CD4053BPWRG4 74HC4053D.653 74LVC2G53DP.125 74HC4052DB.112 74HC4052PW.112 74HC4053DB.112 74HC4067DB.112 74HC4351DB.112 74HCT4052D.112 74HCT4052DB.112 74HCT4053DB.112 74HCT4067D.112 74HCT4351D.112 74LV4051PW.112 FSA1256L8X_F113 PI5V330QE PI5V331QE 5962-8771601EA 5962-87716022A ADG5249FBRUZ ADG1438BRUZ AD7506JNZ AD7506KNZ